

# QDLASER

## QLF063A-85A0 /QLF063D-85A0

685 nm 100mW FP LASER TO-CAN

Preliminary

C00260-01 July 2021



### 1. DESCRIPTION

The QLF063A-85A0/QLF063D-85A0 are 685 nm quantum well laser devices designed for high output power application. The laser diode is mounted into a TO-56 header including a monitor PD and hermetic sealed with a flat glass cap.

### 2. FEATURES

- 685 nm FP-LD
- $\Phi 5.6\text{mm}$  TO-CAN package
- High output power of 100mW and high slope efficiency
- Including monitor PD
- Two types of pin assignments: anode common type (QLF063A-85A0)/cathode common type (QLF063D-85A0)

### 3. APPLICATIONS

- Industrial laser markers
- Measuring instruments
- Life science applications

### 4. ABSOLUTE MAXIMUM RATING

(CW operation,  $T_c = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Optical output power	$P_o$	105	mW
LD reverse voltage	$V_{RLD}$	2	V
PD reverse voltage	$V_{RPD}$	30	V
Operation temperature	$T_c$	-10 to 70	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 to 85	$^\circ\text{C}$

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Ohmstrasse 4  
85716 Unterschleissheim  
[www.imm-photonics.de](http://www.imm-photonics.de)

Tel.: +49 89 3214120  
Fax.: +49 89 32141211  
[sales@imm-photonics.de](mailto:sales@imm-photonics.de)

## 5. OPTICAL AND ELECTRICAL CHARACTERISTICS

(T<sub>c</sub> = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold current	I <sub>th</sub>	CW	-	40	-	mA
Operation current	I <sub>op</sub>	CW, P <sub>o</sub> =100 mW	-	125	-	mA
Operation voltage	V <sub>op</sub>	CW, P <sub>o</sub> =100 mW	-	2.35	-	V
Slope efficiency	η	CW, P <sub>o</sub> =5 - 100 mW	-	1.17	-	W/A
Monitor current	I <sub>m</sub>	CW, P <sub>o</sub> =100 mW,	-	TBD	-	μA
Peak wavelength	λ <sub>p</sub>	CW, P <sub>o</sub> =100 mW	-	685	-	nm
Beam divergence* Horizontal	θ <sub>h</sub>	CW, P <sub>o</sub> =100 mW	-	9	-	deg.
Beam divergence* vertical	θ <sub>v</sub>	CW, P <sub>o</sub> =100 mW	-	14	-	deg.
Beam angle Horizontal	Δθ <sub>h</sub>	CW, P <sub>o</sub> =100 mW	-3	-	3	deg.
Beam angle vertical	Δθ <sub>v</sub>	CW, P <sub>o</sub> =100 mW	-3	-	3	deg.

\*Beam divergence is FWHM of far field pattern.

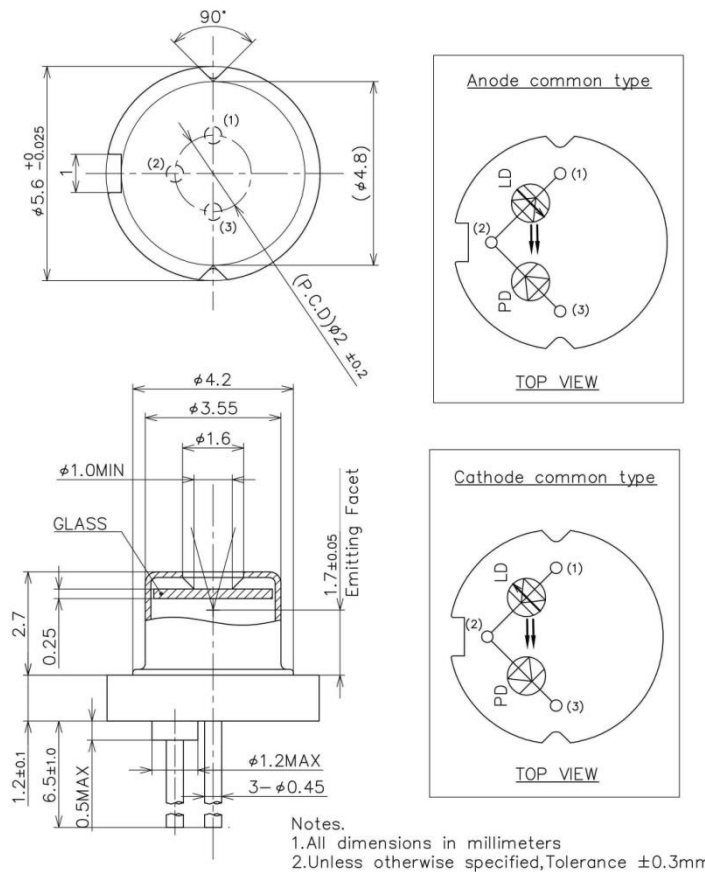
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## 6. OUTLINE DRAWINGS



## 7. NOTICE

- Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10.

Please do not take a look at laser lighting in operations since laser devices may cause troubles to human eyes.

Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

- Handling products

Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD. Please pay attention to handling products, and use within range of maximum ratings. QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

- RoHS

This product conforms to RoHS compliance related Directive (EU) 2015/863.

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QD Laser, Inc.

Contact : [info@qdlaser.com](mailto:info@qdlaser.com) <http://www.qdlaser.com>

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Keihin Bldg. 1F 1-1 Minamiwatarida-cho, Kawasaki-ku, Kawasaki, Kanagawa Zip 210-0855 Japan

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